

FEATURES

Passive: no dc bias required
Input IP3: 20 dBm typical, downconverter
LO to RF isolation: 30 dB typical
Wide IF bandwidth: dc to 8 GHz
12-terminal, ceramic, 2.90 mm × 2.90 mm LCC

APPLICATIONS

Point to point radios
Point to multipoint radios and very small aperture terminals (VSATs)
Test equipment and sensors
Military end use

GENERAL DESCRIPTION

The HMC774ALC3B is a general-purpose, double balanced mixer in a leadless, RoHS compliant, surface-mount package that can be used as an upconverter or a downconverter between 7 GHz and 34 GHz. This mixer requires no external components or matching circuitry. The HMC774ALC3B provides excellent LO to RF isolation and LO to IF isolation due to optimized balun structures.

FUNCTIONAL BLOCK DIAGRAM

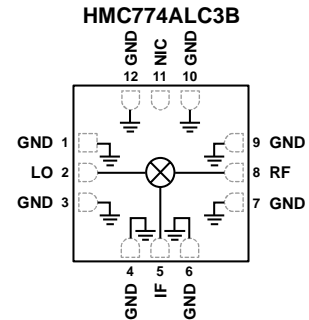


Figure 1.

The mixer operates best with a LO drive level of 15 dBm (typical). The HMC774ALC3B eliminates the need for wire bonding, allowing the use of surface-mount manufacturing techniques.

Rev. A

[Document Feedback](#)

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REVISION HISTORY

6/2018—Rev. 0 to Rev. A

| | | | |
|---|----|---|----|
| Change to General Description Section and Features Section .. | 1 | Changed Upconverter, IF = 500 MHz Section to Upconverter, IF = 500 MHz, Upper Sideband Section | 14 |
| Change to Table 1 and Table 2 | 3 | Added Figure 48, Figure 49, Figure 51, and Figure 52 | 14 |
| Change to Table 5 | 5 | Added Upconverter, IF = 500 MHz, Lower Sideband Section | 15 |
| Changed Downconverter, IF = 500 MHz Section to Downconverter, IF = 500 MHz, Upper Sideband Section | 6 | Added Figure 54, Figure 55, Figure 57 and Figure 58 | 15 |
| Changes to Figure 7 to Figure 12 | 6 | Added Upconverter, IF = 3000 MHz, Upper Sideband Section | 16 |
| Changes to Figure 13 | 7 | Added Figure 59 to Figure 62 | 16 |
| Added Figure 14; Renumbered Sequentially | 7 | Added Upconverter, IF = 3000 MHz, Lower Sideband Section | 17 |
| Added Downconverter, IF = 500 MHz, Lower Sideband Section | 8 | Added Figure 63 to Figure 66 | 17 |
| Added Figure 15 to Figure 20 | 8 | Added Upconverter, IF = 8000 MHz, Upper Sideband Section | 18 |
| Added Figure 21 and Figure 22 | 9 | Added Figure 67 to Figure 70 | 18 |
| Added Downconverter, IF = 3000 MHz, Upper Sideband Section | 10 | Added Upconverter, IF = 8000 MHz, Lower Sideband Section | 19 |
| Changes to Figure 23 and Figure 24 | 10 | Added Figure 71 to Figure 74 | 19 |
| Added Downconverter, IF = 3000 MHz, Upper Sideband Section | 10 | Changed IF Bandwidth Section to IF Bandwidth, LO = 28 GHz, Upper Sideband Section | 20 |
| Added Figure 25 to Figure 28 | 10 | Added Figure 75 to Figure 80 | 20 |
| Added Downconverter, IF = 3000 MHz, Lower Sideband Section | 11 | Added IF Bandwidth, LO = 34 GHz, Lower Sideband Section | 20 |
| Added Figure 29 to Figure 34 | 11 | Added Figure 81 to Figure 86 | 21 |
| Added Downconverter, IF = 8000 MHz, Upper Sideband Section | 12 | Changes to Spurious Performance Section and Table 6 | 23 |
| Added Figure 35 to Figure 40 | 12 | Added Table 7; Renumbered Sequentially | 23 |
| Added Downconverter, IF = 8000 MHz, Lower Sideband Section | 13 | | |
| Added Figure 41 to Figure 46 | 13 | | |

2/2018—Revision 0: Initial Version

SPECIFICATIONS

7 GHz TO 20 GHz FREQUENCY RANGE

Measurements are performed in downconverter mode at $T_A = 25^\circ\text{C}$, IF frequency (f_{IF}) = 500 MHz, RF power (P_{RF}) = -10 dBm, LO power (P_{LO}) = +15 dBm, and upper sideband (USB) with 50 Ω system, unless otherwise noted.

Table 1.

| Parameter | Symbol | Min | Typ | Max | Unit |
|------------------------------|----------|------|-----|-----|------|
| FREQUENCY RANGE | | | | | |
| Radio Frequency | f_{RF} | 7 | | 20 | GHz |
| Intermediate Frequency | f_{IF} | DC | | 8 | GHz |
| Local Oscillator | f_{LO} | 7 | | 34 | GHz |
| LO DRIVE LEVEL | | 11 | 15 | 17 | dBm |
| RF PERFORMANCE | | | | | |
| Downconverter | | | | | |
| Conversion Loss | | | 10 | 15 | dB |
| Input Third-Order Intercept | IP3 | 12.5 | 20 | | dBm |
| Input Second-Order Intercept | IP2 | | 48 | | dBm |
| Input 1 dB Compression Point | P1dB | | 12 | | dB |
| Single Sideband Noise Figure | SSB NF | | 12 | | dB |
| Isolation | | | | | |
| RF to IF | | 7 | 9 | | dB |
| LO to RF | | 28 | 30 | | dB |
| LO to IF | | 20.5 | 23 | | dB |
| Upconverter | | | | | |
| Conversion Loss | | | 10 | | dB |
| Input Third-Order Intercept | IP3 | | 27 | | dBm |

20 GHz TO 34 GHz FREQUENCY RANGE

Measurements are performed in downconverter mode at $T_A = 25^\circ\text{C}$, $f_{IF} = 500$ MHz, $P_{RF} = -10$ dBm, $P_{LO} = +15$ dBm, and lower sideband with 50 Ω system, unless otherwise noted.

Table 2.

| Parameter | Symbol | Min | Typ | Max | Unit |
|------------------------------|----------|------|-----|------|------|
| FREQUENCY RANGE | | | | | |
| Radio Frequency | f_{RF} | 20 | | 34 | GHz |
| Intermediate Frequency | f_{IF} | DC | | 8 | GHz |
| Local Oscillator | f_{LO} | 20 | | 34 | GHz |
| LO DRIVE LEVEL | | 11 | 15 | 17 | dBm |
| RF PERFORMANCE | | | | | |
| Downconverter | | | | | |
| Conversion Loss | | | 12 | 15.5 | dB |
| Input Third-Order Intercept | IP3 | 17 | 20 | | dBm |
| Input Second-Order Intercept | IP2 | | 40 | | dBm |
| Input 1 dB Compression Point | P1dB | | 13 | | dB |
| Single Sideband Noise Figure | SSB NF | | 12 | | dB |
| Isolation | | | | | |
| RF to IF | | 25 | 30 | | dB |
| LO to RF | | 27.5 | 33 | | dB |
| LO to IF | | 30 | 40 | | dB |
| Upconverter | | | | | |
| Conversion Loss | | | 9 | | dB |
| Input Third-Order Intercept | IP3 | | 23 | | dBm |

ABSOLUTE MAXIMUM RATINGS

Table 3.

| Parameter | Rating |
|---|--------------------|
| RF Input Power when LO = 18 dBm | 21 dBm |
| LO Drive | 25 dBm |
| IF Input Power when LO = 18 dBm | 21 dBm |
| LO and RF DC Source and Sink Current | 55 mA |
| IF Port Maximum Sink and Source Current | 3 mA |
| Maximum Channel Temperature | 175°C |
| Maximum Junction Temperature | 165°C |
| Continuous Power Dissipation, P_{DISS} ($T_A = 85^\circ\text{C}$, Derate 2.9 mW/°C Above 85°C) | 189 mW |
| Operating Temperature Range | -40°C to +85°C |
| Storage Temperature Range | -65°C to +150°C |
| Lead Temperature Range | -65°C to +150°C |
| Reflow Temperature | 260°C |
| Electrostatic Discharge (ESD) Sensitivity | |
| Human Body Model (HBM) | Class 1C (1.5 kV) |
| Field Induced Charge Device Model (FICDM) | Class IV (1.25 kV) |

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

THERMAL RESISTANCE

Thermal performance is directly linked to printed circuit board (PCB) design and operating environment. Careful attention to PCB thermal design is required.

θ_{JA} is the thermal resistance value that is measured from junction to air, and θ_{JC} is the thermal resistance value that is measured from junction to case (package).

Table 4. Thermal Resistance

| Package Type ¹ | θ_{JA} | θ_{JC} | Unit |
|---------------------------|---------------|---------------|------|
| E-12-4 | 120 | 274 | °C/W |

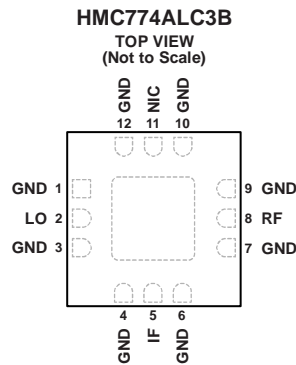
¹ See JEDEC standard JESD51-2 for additional information on optimizing the thermal impedance (PCB with 3 × 3 vias).

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS



- NOTES**
1. NIC = NOT INTERNALLY CONNECTED. THESE PINS CAN BE CONNECTED TO RF AND DC GROUND. PERFORMANCE IS NOT AFFECTED.
 2. EXPOSED PAD. THE EXPOSED PAD MUST BE CONNECTED TO THE RF AND DC GROUND OF THE PCB.

13897-002

Figure 2. Pin Configuration

Table 5. Pin Function Descriptions

| Pin No. | Mnemonic | Description |
|--------------------------|----------|---|
| 1, 3, 4, 6, 7, 9, 10, 12 | GND | Ground. These pins must be connected to the RF and dc ground of the PCB. See Figure 3 for the interface schematic. |
| 2 | LO | Local Oscillator Port. This pin is dc-coupled and matched to 50 Ω. For the maximum dc current capability of this pin, see the Absolute Maximum Ratings section. See Figure 4 for the interface schematic. |
| 5 | IF | Intermediate Frequency Port. For applications not requiring operation to dc, dc block this port externally using a series capacitor of a value chosen to pass the necessary IF frequency range. For operation to dc, this pin must not source or sink more than 3 mA of current or die malfunction and possible die failure can result. See Figure 5 for the interface schematic. |
| 8 | RF | Radio Frequency Port. This pin is dc-coupled and matched to 50 Ω. For the maximum dc current capability of this pin, see the Absolute Maximum Ratings section. See Figure 6 for the interface schematic. |
| 11 | NIC | Not Internally Connected. These pins can be connected to RF and dc ground. Performance is not affected. |
| | EPAD | Exposed Pad. The exposed pad must be connected to the RF and dc ground of the PCB. |

INTERFACE SCHEMATICS



Figure 3. GND Interface Schematic

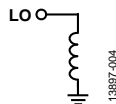


Figure 4. LO Interface Schematic

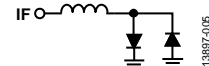


Figure 5. IF Interface Schematic

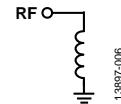


Figure 6. RF Interface Schematic

TYPICAL PERFORMANCE CHARACTERISTICS

DOWNCONVERTER, IF = 500 MHz, UPPER SIDEBAND

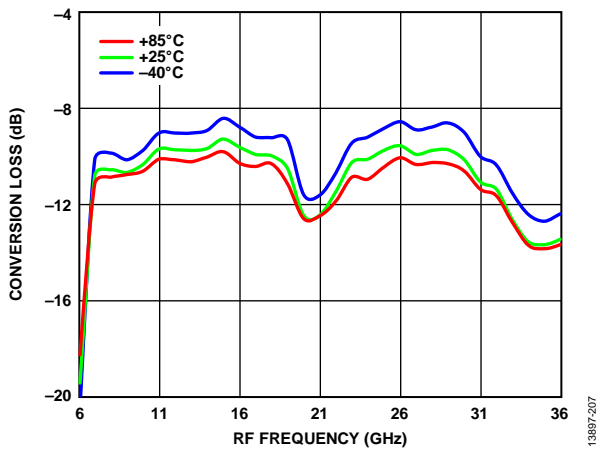


Figure 7. Conversion Loss vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

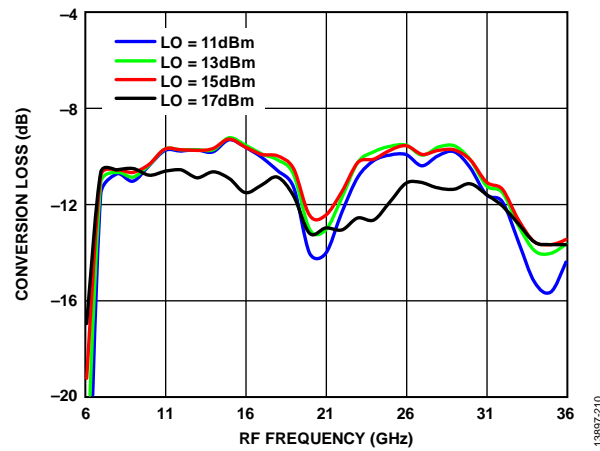


Figure 10. Conversion Loss vs. RF Frequency over LO Drives

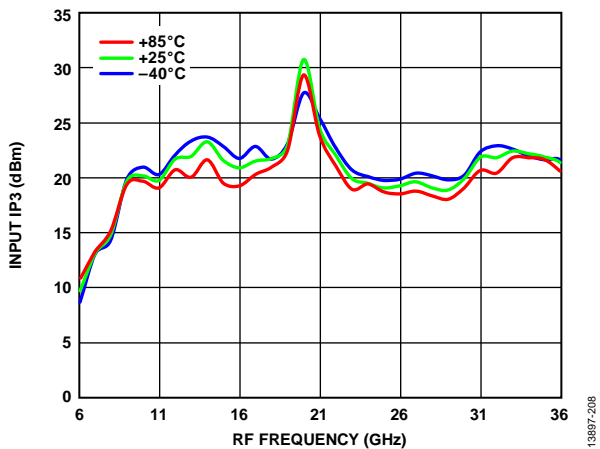


Figure 8. Input IP3 vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

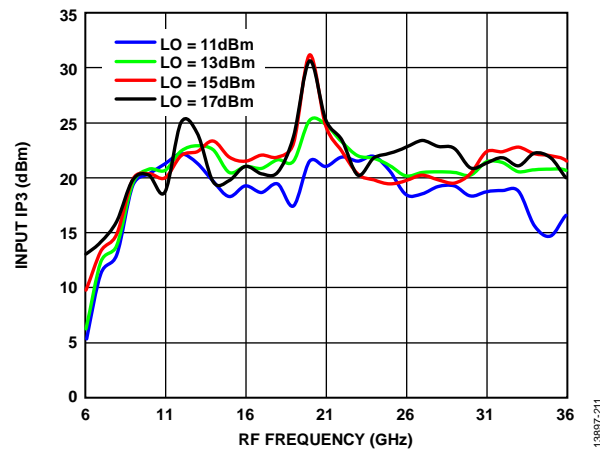


Figure 11. Input IP3 vs. RF Frequency over Various LO Drives

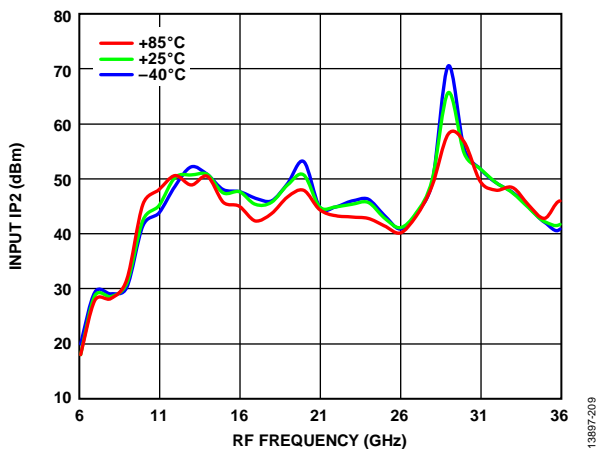


Figure 9. Input IP2 vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

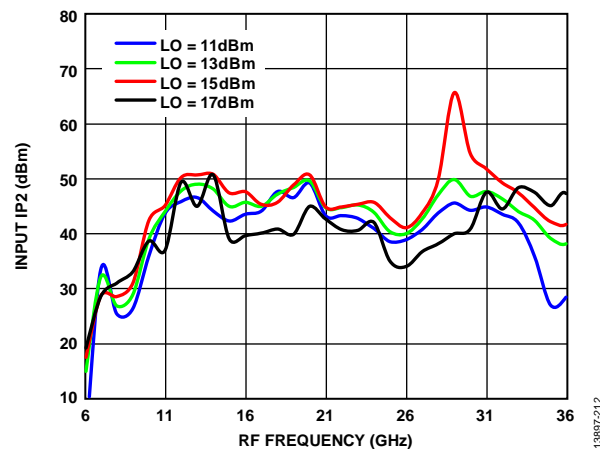


Figure 12. Input IP2 vs. RF Frequency over Various LO Drives

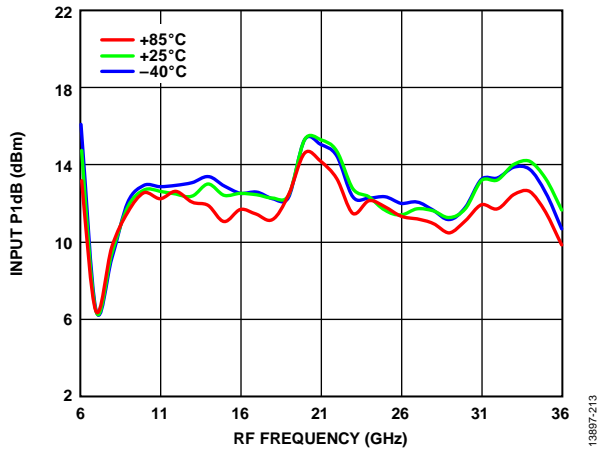


Figure 13. Input P1dB vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

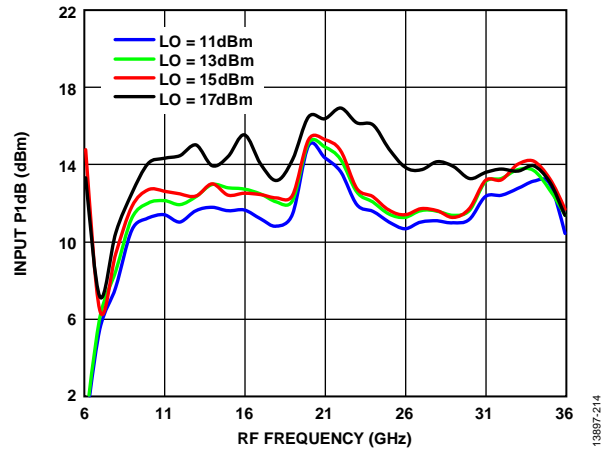


Figure 14. Input P1dB vs. RF Frequency over Various LO Drives

DOWNCONVERTER, IF = 500 MHz, LOWER SIDEBAND

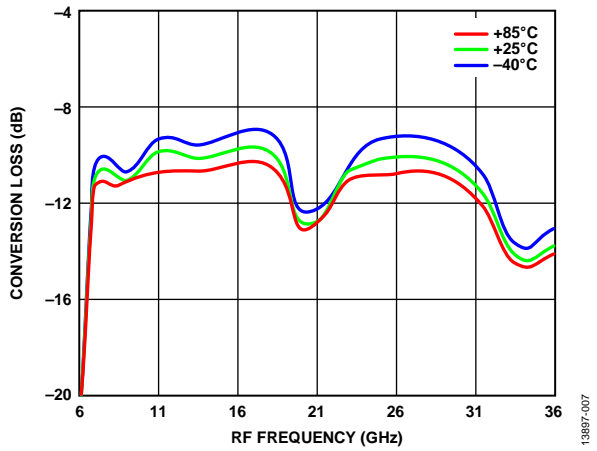


Figure 15. Conversion Loss vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

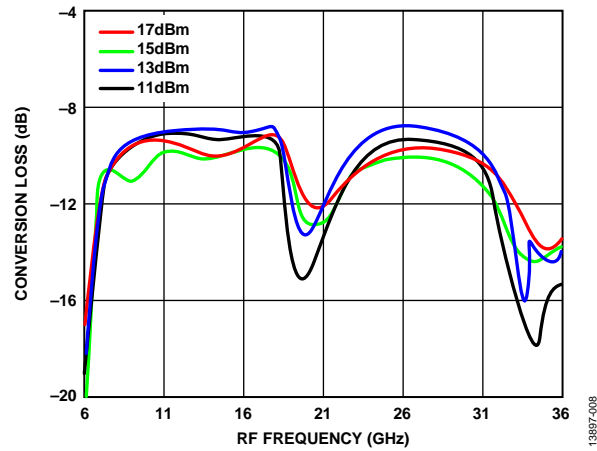


Figure 18. Conversion Loss vs. RF Frequency over LO Drives

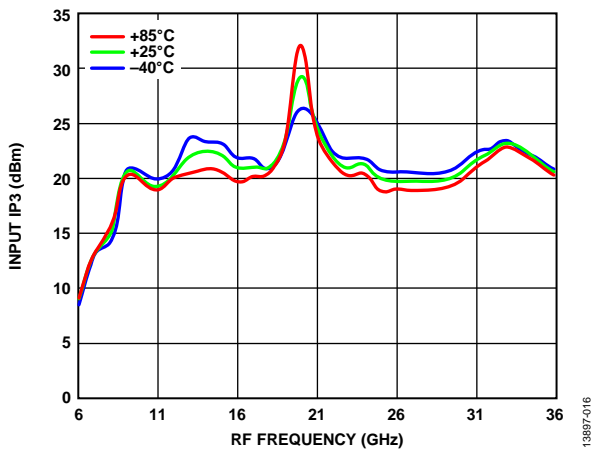


Figure 16. Input IP3 vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

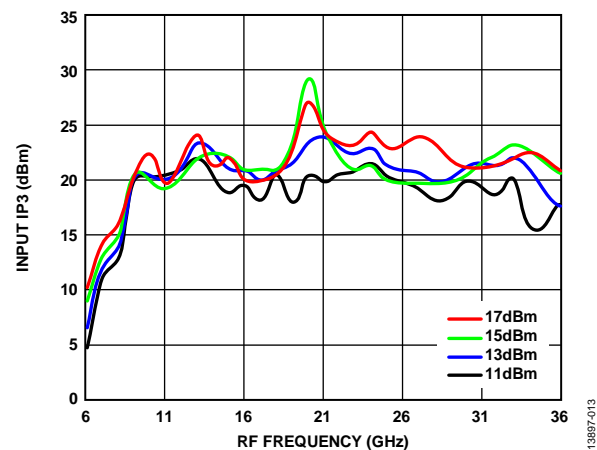


Figure 19. Input IP3 vs. RF Frequency over Various LO Drives

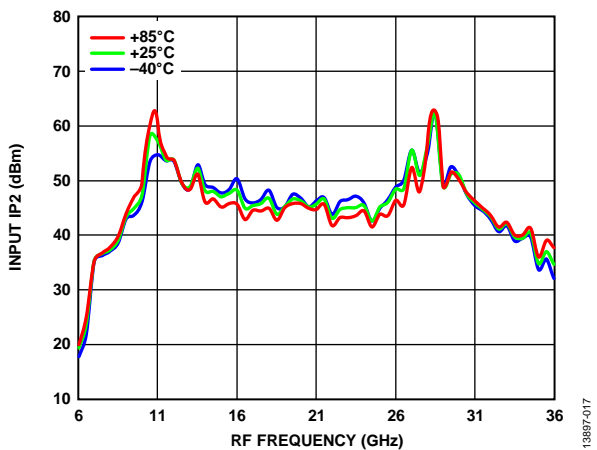


Figure 17. Input IP2 vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

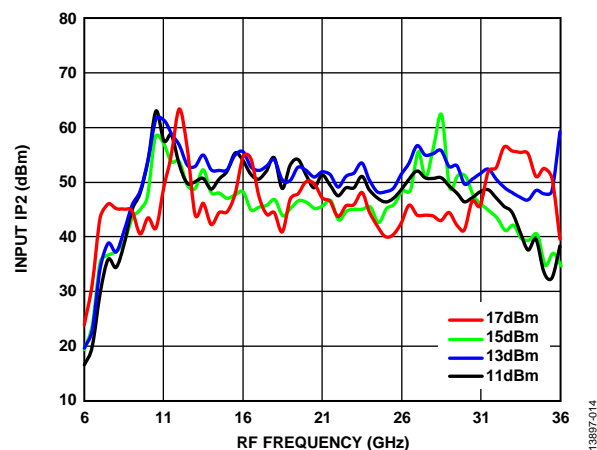


Figure 20. Input IP2 vs. RF Frequency over Various LO Drives

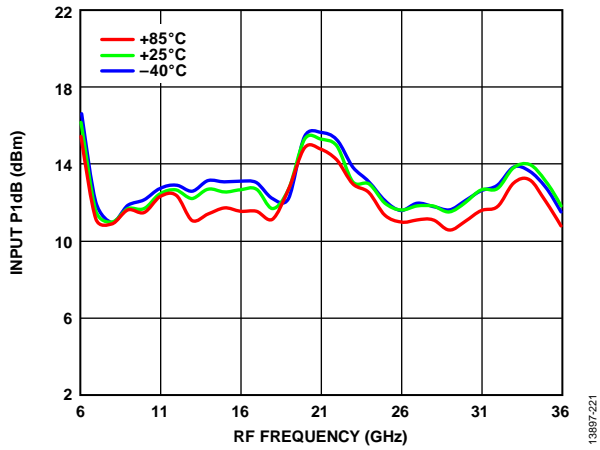


Figure 21. Input P1dB vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

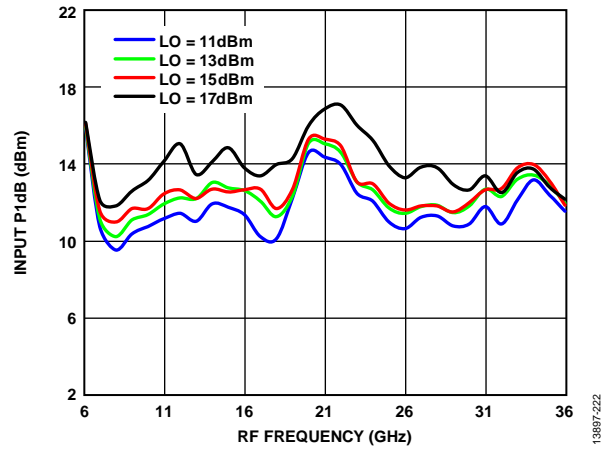


Figure 22. Input P1dB vs. RF Frequency over Various LO Drives

DOWNCONVERTER, IF = 3000 MHz, UPPER SIDEBAND

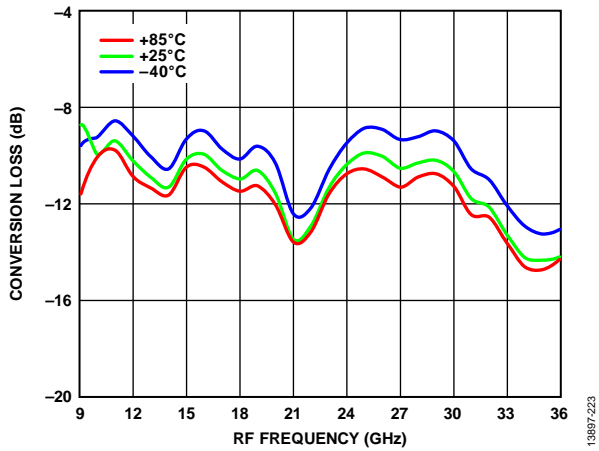


Figure 23. Conversion Loss vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

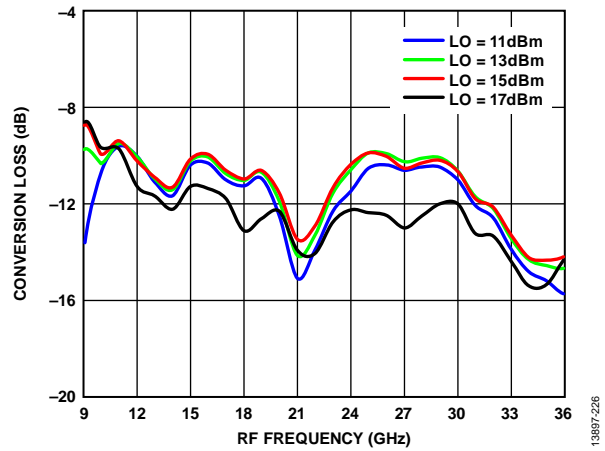


Figure 26. Conversion Loss vs. RF Frequency over Various LO Drives

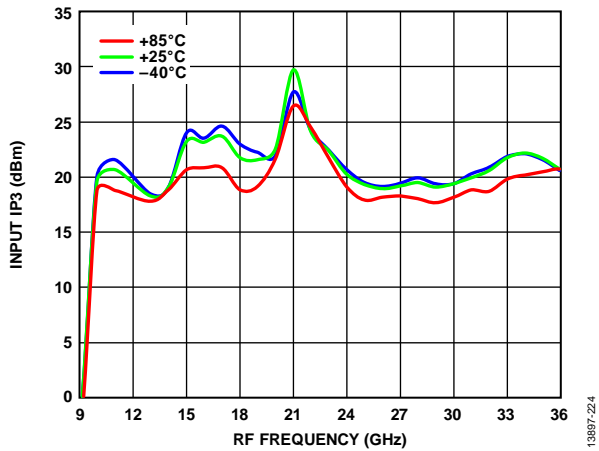


Figure 24. Input IP3 vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

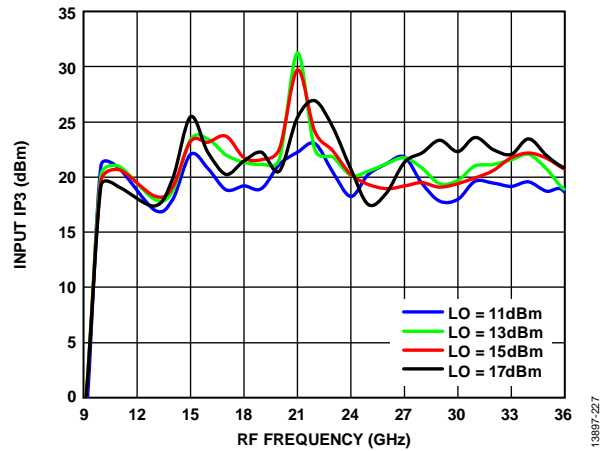


Figure 27. Input IP3 vs. RF Frequency over Various LO Drives

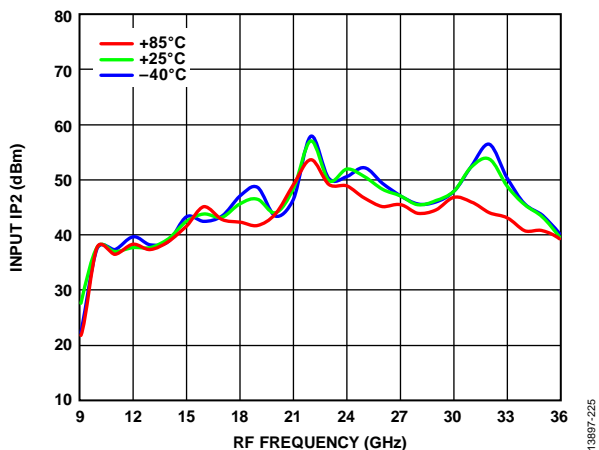


Figure 25. Input IP2 vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

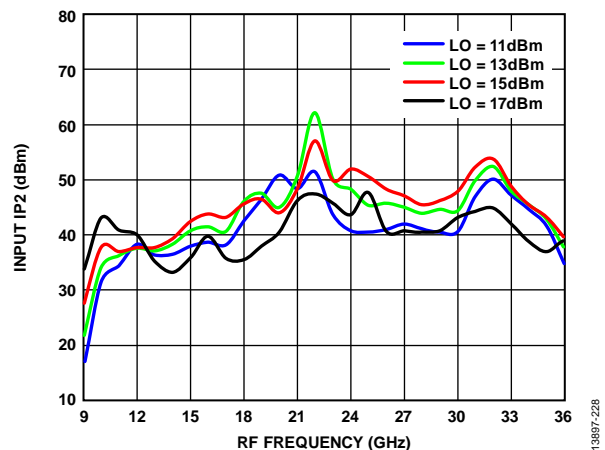


Figure 28. Input IP2 vs. RF Frequency over Various LO Drives

DOWNCONVERTER, IF = 3000 MHz, LOWER SIDEBAND

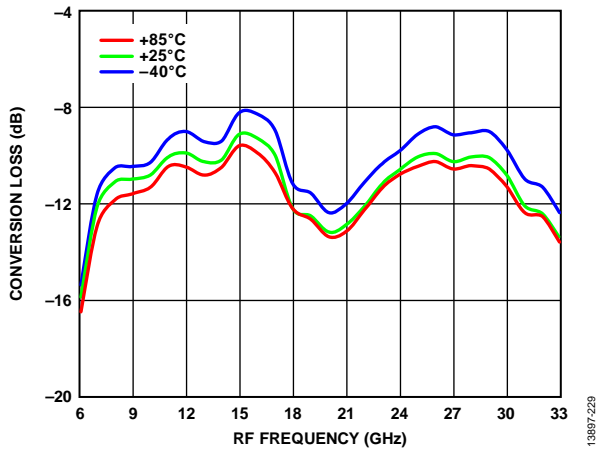


Figure 29. Conversion Loss vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

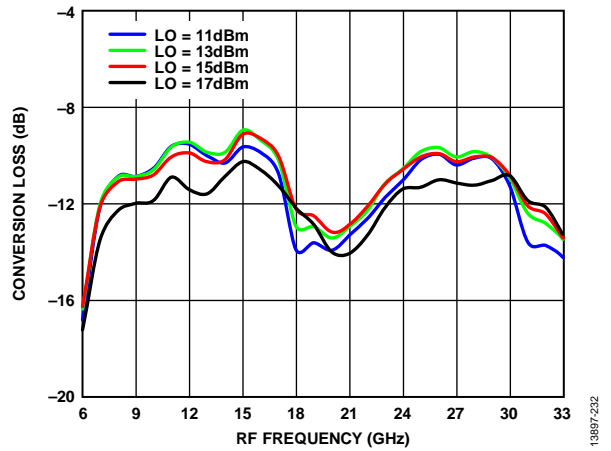


Figure 32. Conversion Loss vs. RF Frequency over Various LO Drives

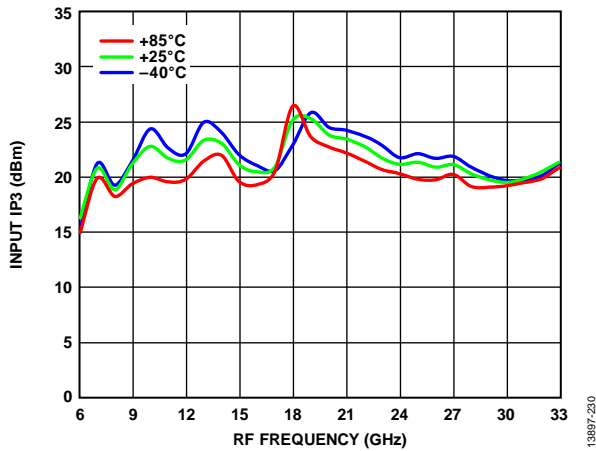


Figure 30. Input IP3 vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

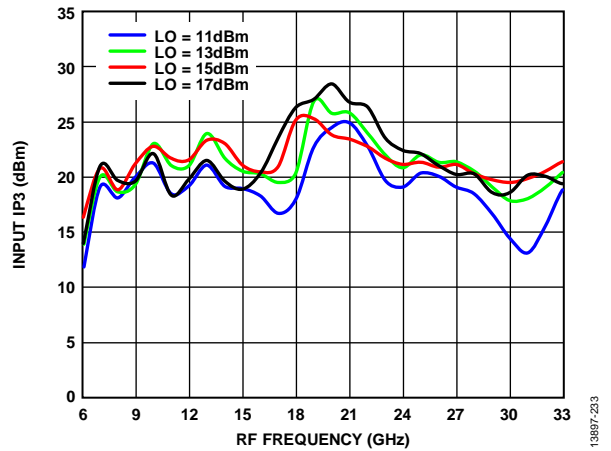


Figure 33. Input IP3 vs. RF Frequency over Various LO Drives

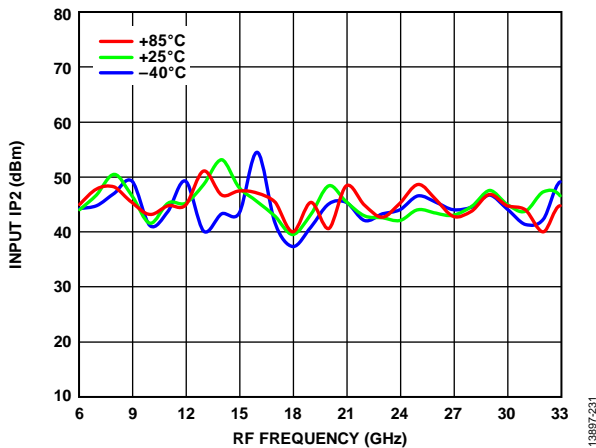


Figure 31. Input IP2 vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

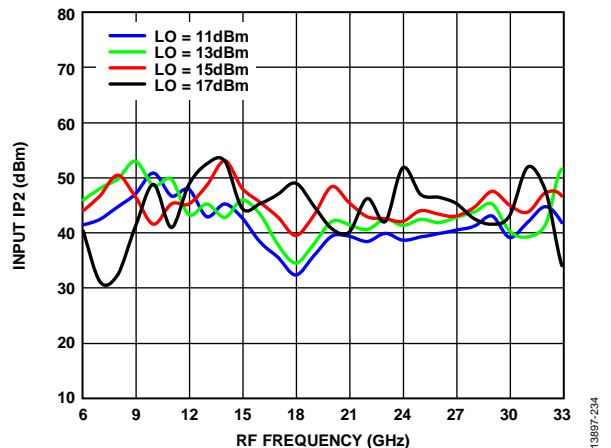


Figure 34. Input IP2 vs. RF Frequency over Various LO Drives

DOWNCONVERTER, IF = 8000 MHz, UPPER SIDEBAND

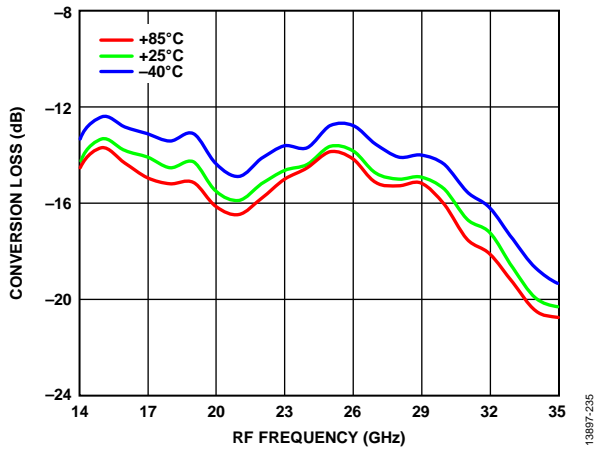


Figure 35. Conversion Loss vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

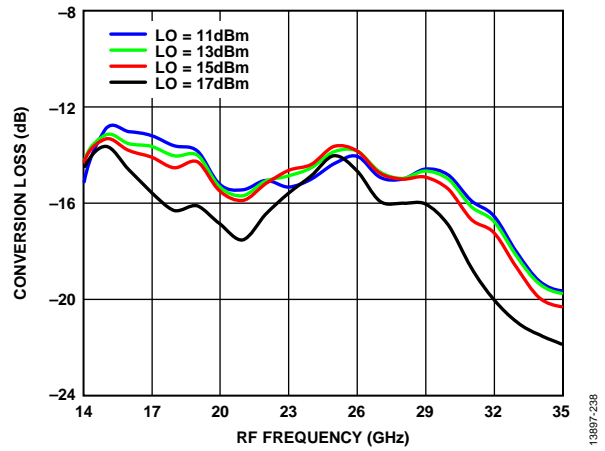


Figure 38. Conversion Loss vs. RF Frequency over Various LO Drives

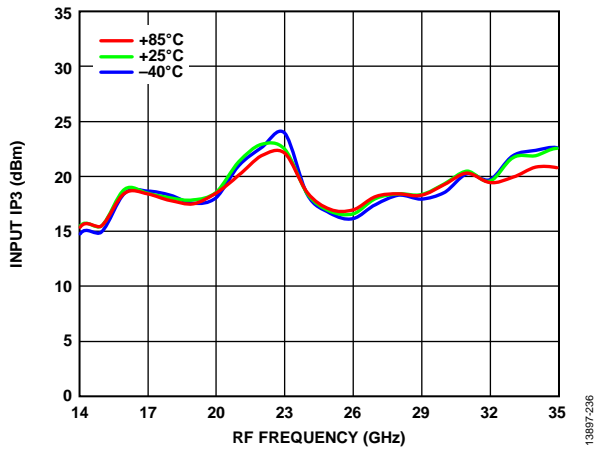


Figure 36. Input IP3 vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

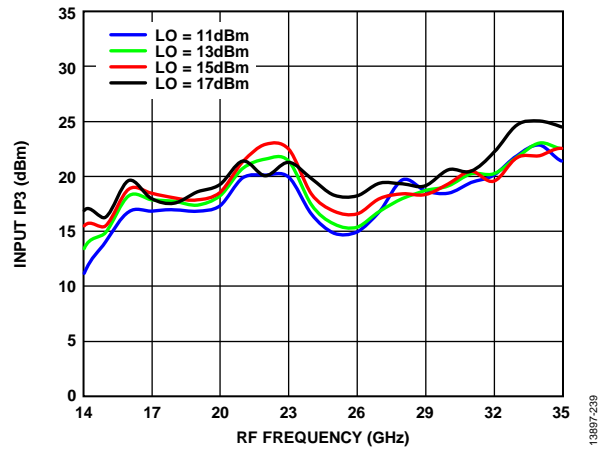


Figure 39. Input IP3 vs. RF Frequency over Various LO Drives

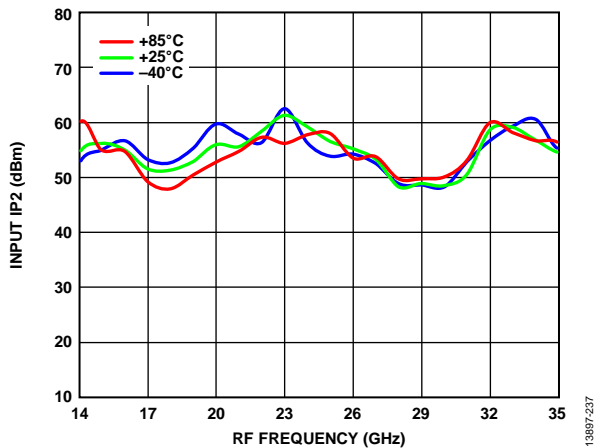


Figure 37. Input IP2 vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

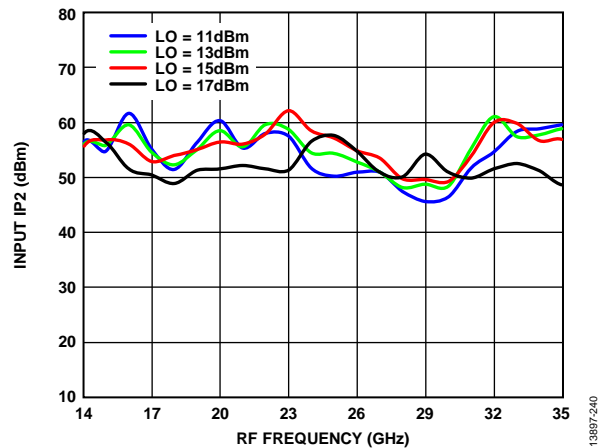


Figure 40. Input IP2 vs. RF Frequency over Various LO Drives

DOWNCONVERTER, IF = 8000 MHz, LOWER SIDEBAND

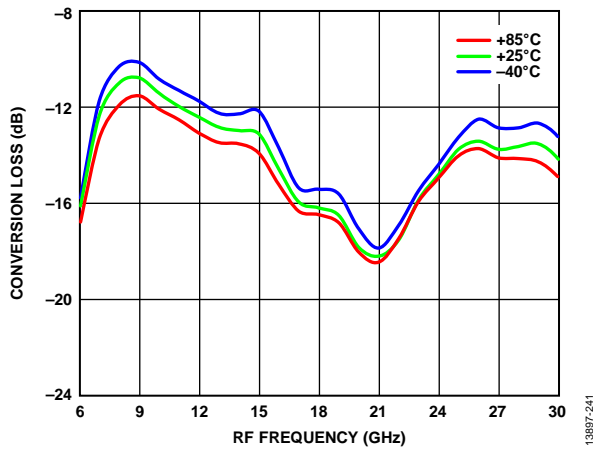


Figure 41. Conversion Loss vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

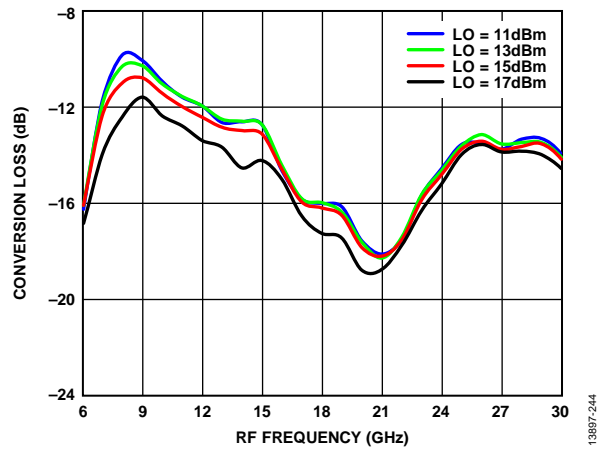


Figure 44. Conversion Loss vs. RF Frequency over Various LO Drives

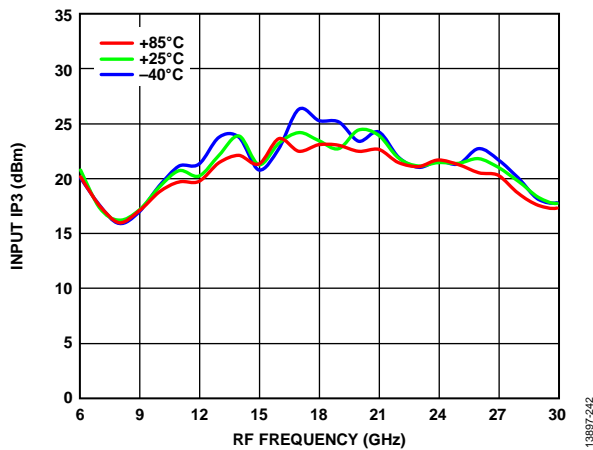


Figure 42. Input IP3 vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

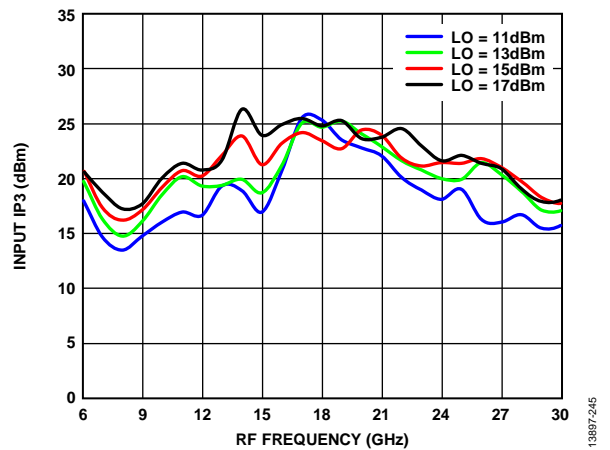


Figure 45. Input IP3 vs. RF Frequency over Various LO Drives

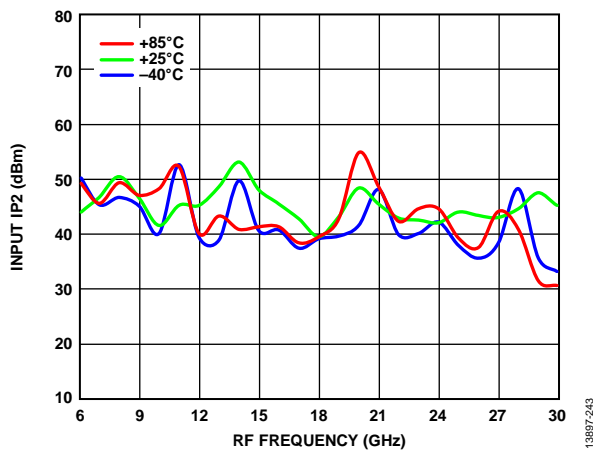


Figure 43. Input IP2 vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

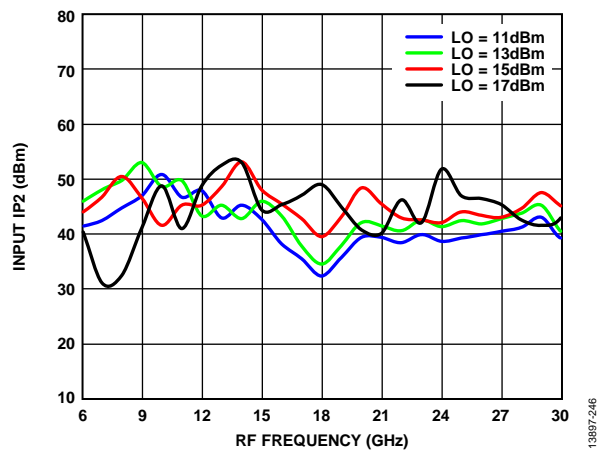


Figure 46. Input IP2 vs. RF Frequency over Various LO Drives

UPCONVERTER, IF = 500 MHz, UPPER SIDEBAND

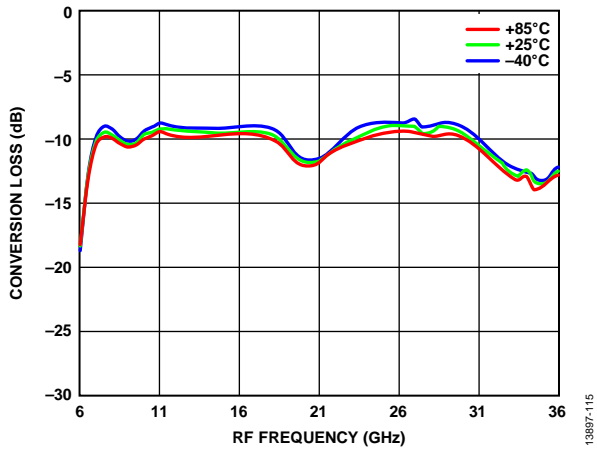


Figure 47. Conversion Loss vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

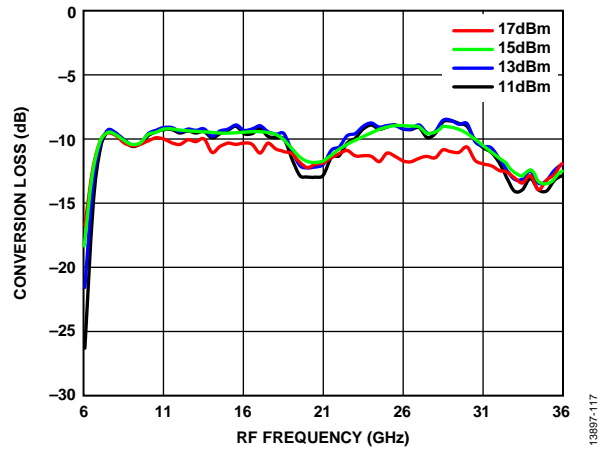


Figure 50. Conversion Loss vs. RF Frequency over LO Drives

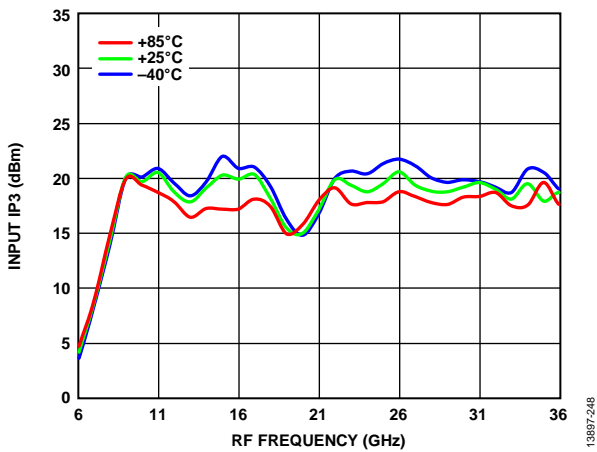


Figure 48. Input IP3 vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

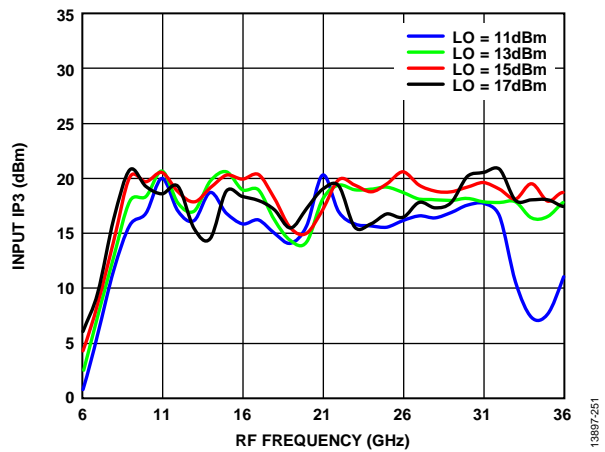


Figure 51. Input IP3 vs. RF Frequency over Various LO Drives

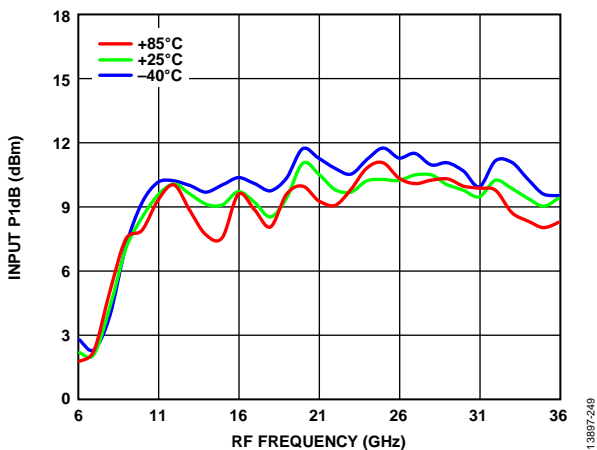


Figure 49. Input P1dB vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

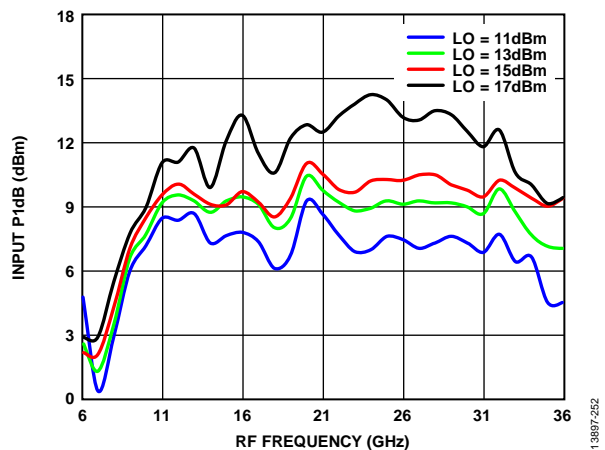


Figure 52. Input P1dB vs. RF Frequency over Various LO Drives

UPCONVERTER, IF = 500 MHz, LOWER SIDEBAND

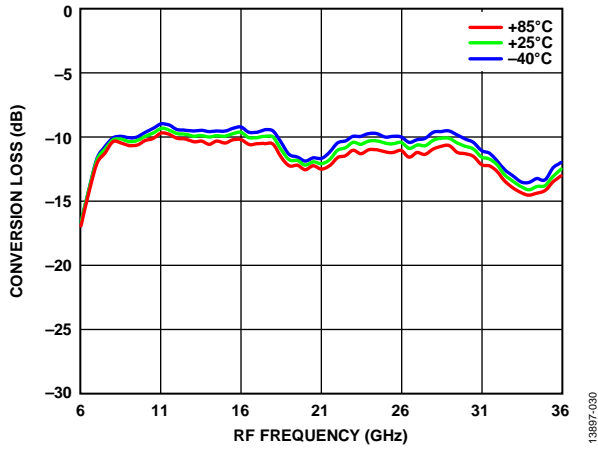


Figure 53. Conversion Loss vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

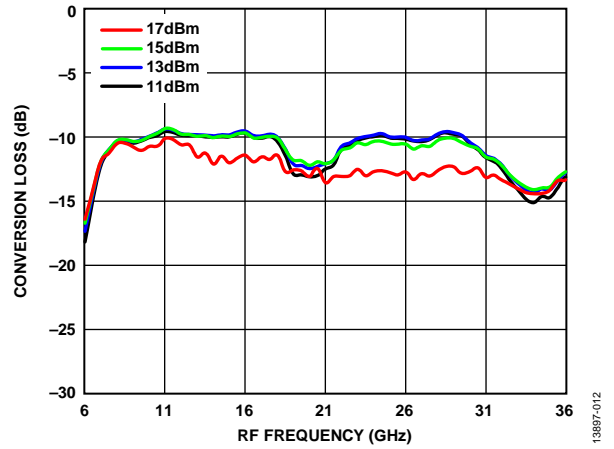


Figure 56. Conversion Loss vs. RF Frequency over LO Drives

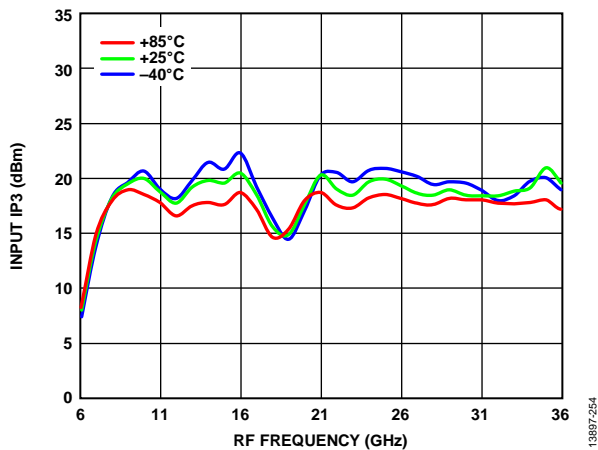


Figure 54. Input IP3 vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

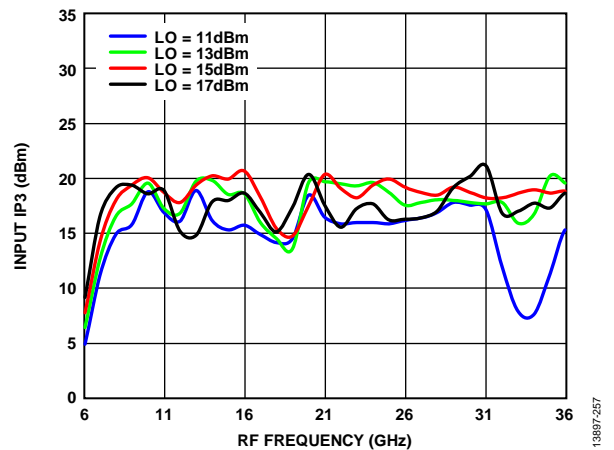


Figure 57. Input IP3 vs. RF Frequency over Various LO Drives

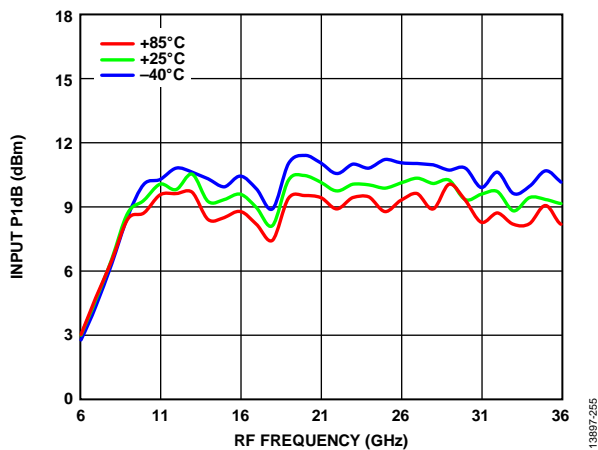


Figure 55. Input P1dB vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

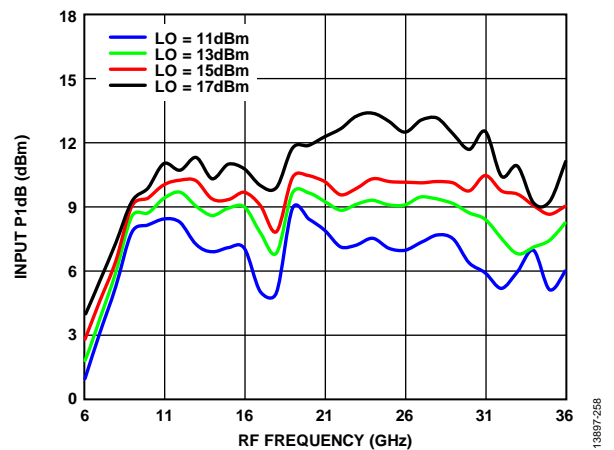


Figure 58. Input P1dB vs. RF Frequency over Various LO Drives

UPCONVERTER, IF = 3000 MHz, UPPER SIDEBAND

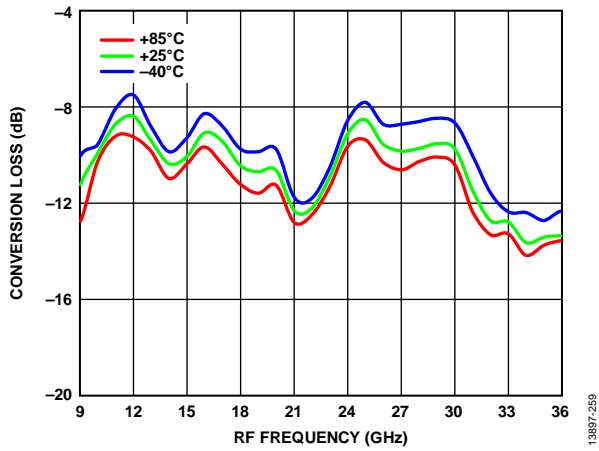


Figure 59. Conversion Loss vs. RF Frequency over Various Temperatures, $P_{LO} = 15$ dBm

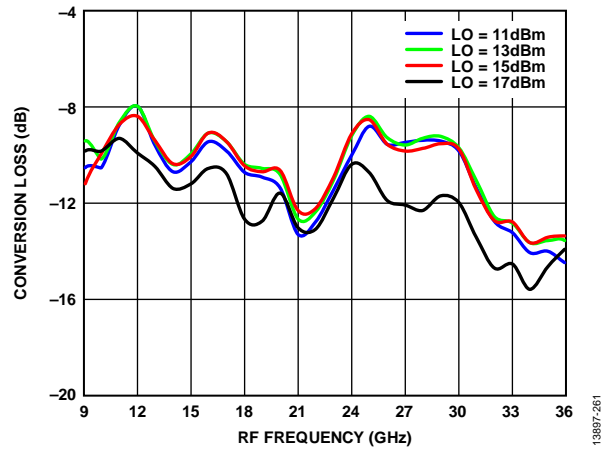


Figure 61. Conversion Loss vs. RF Frequency over LO Drives

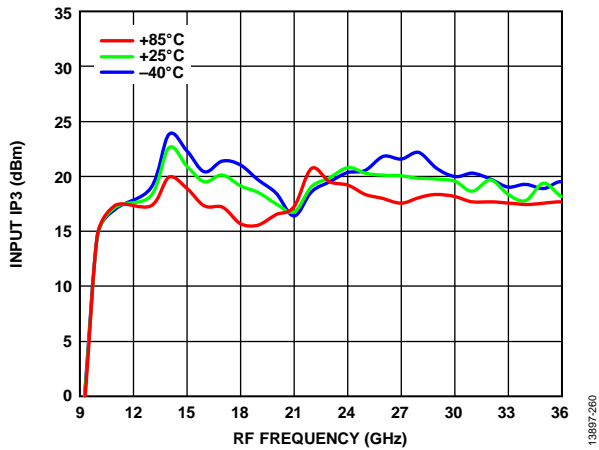


Figure 60. Input IP3 vs. RF Frequency over Various Temperatures, $P_{LO} = 15$ dBm

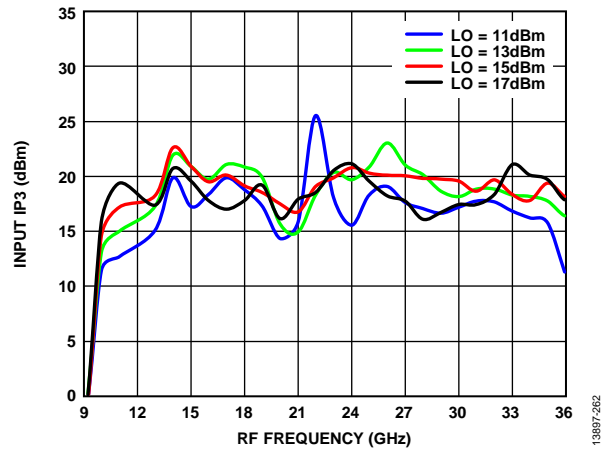


Figure 62. Input IP3 vs. RF Frequency over Various LO Drives

UPCONVERTER, IF = 3000 MHz, LOWER SIDEBAND

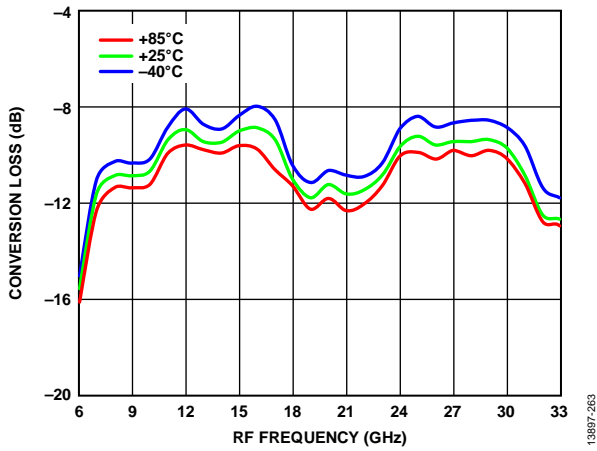


Figure 63. Conversion Loss vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

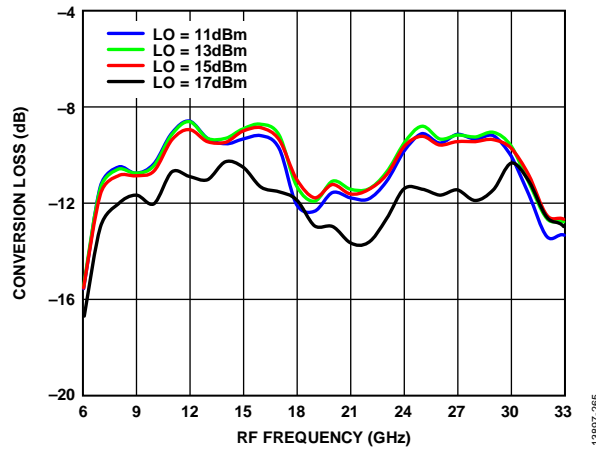


Figure 65. Conversion Loss vs. RF Frequency over LO Drives

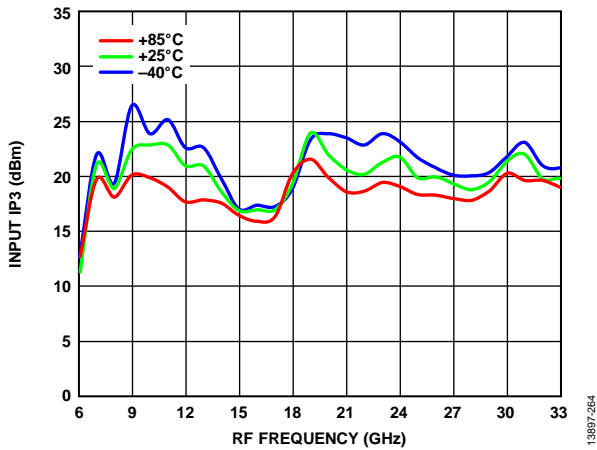


Figure 64. Input IP3 vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

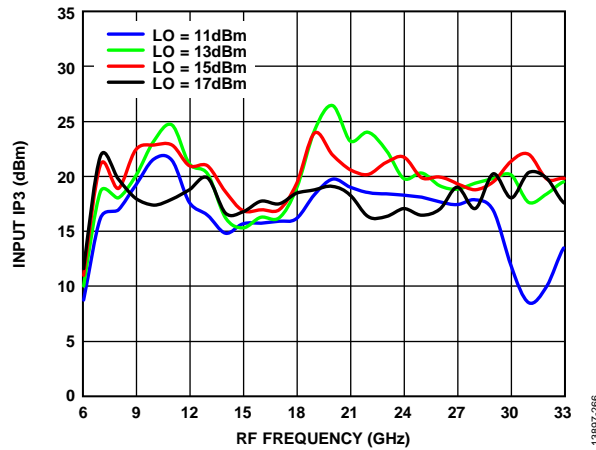


Figure 66. Input IP3 vs. RF Frequency over Various LO Drives

UPCONVERTER, IF = 8000 MHz, UPPER SIDEBAND

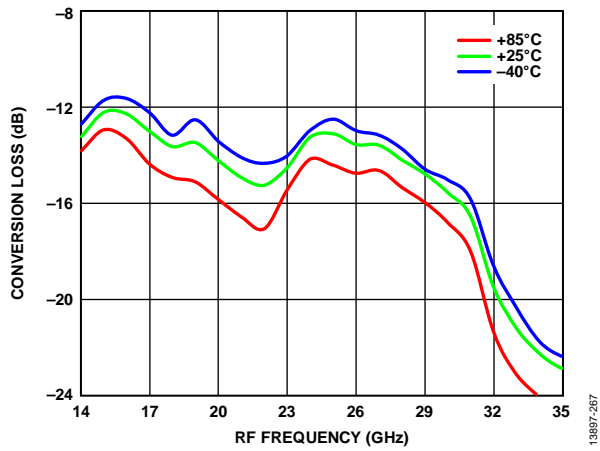


Figure 67. Conversion Loss vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

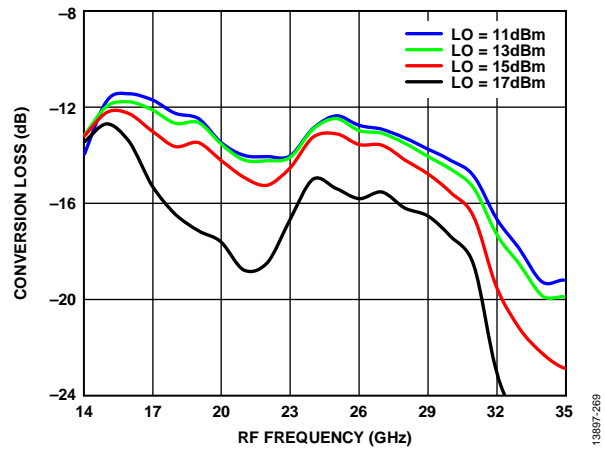


Figure 69. Conversion Loss vs. RF Frequency over LO Drives

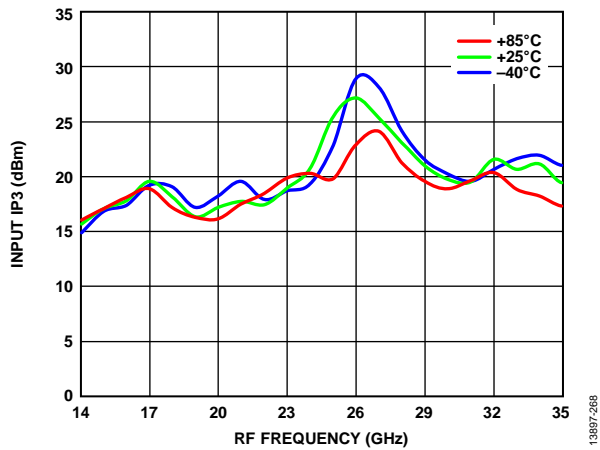


Figure 68. Input IP3 vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

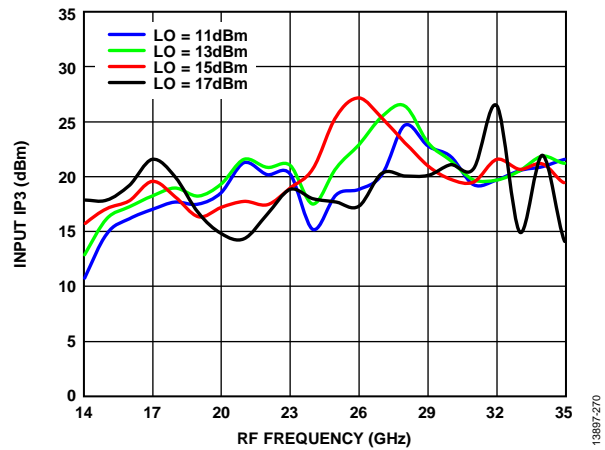


Figure 70. Input IP3 vs. RF Frequency over Various LO Drives

UPCONVERTER, IF = 8000 MHz, LOWER SIDEBAND

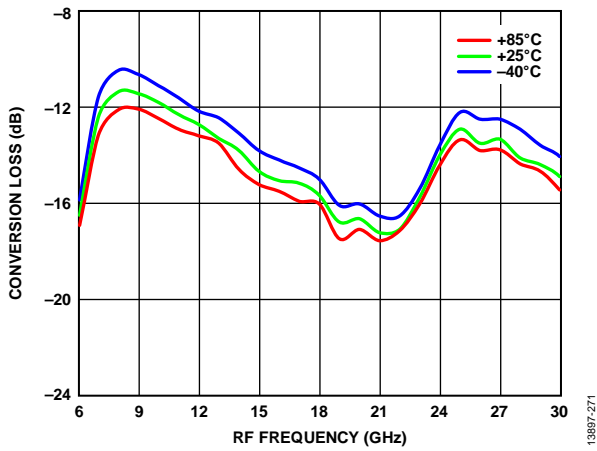


Figure 71. Conversion Loss vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

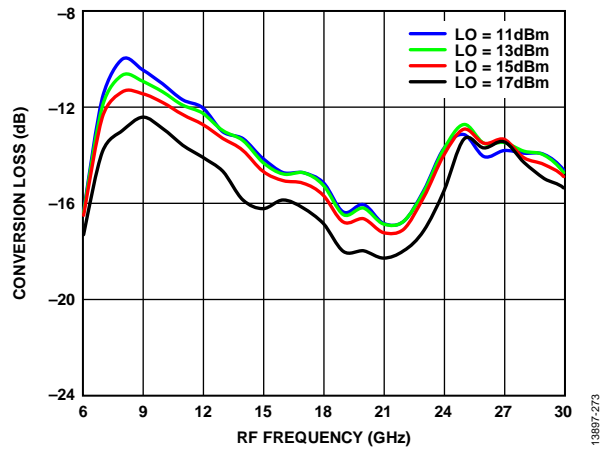


Figure 73. Conversion Loss vs. RF Frequency over LO Drives

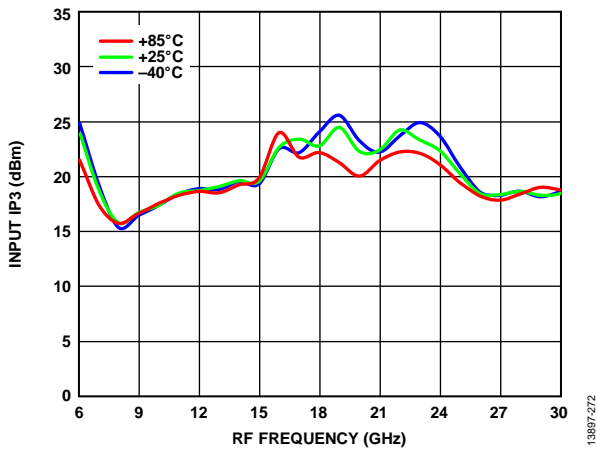


Figure 72. Input IP3 vs. RF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

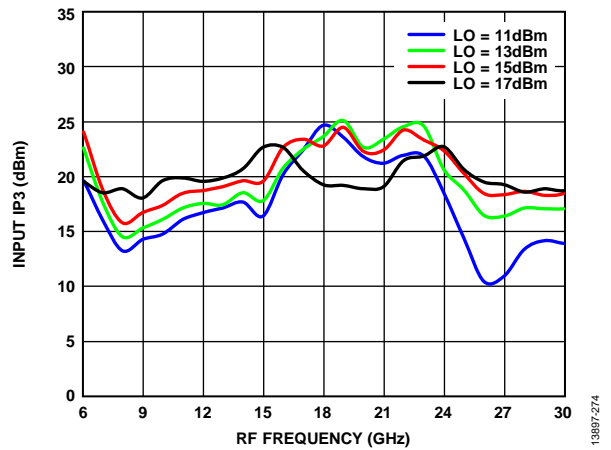


Figure 74. Input IP3 vs. RF Frequency over Various LO Drives

IF BANDWIDTH, LO = 28 GHz, UPPER SIDEBAND

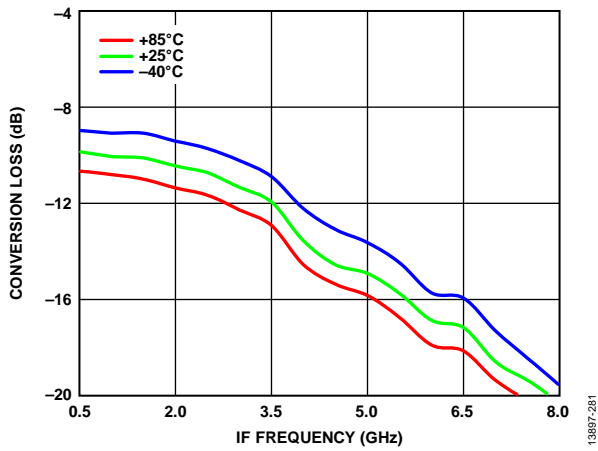


Figure 75. Conversion Loss vs. IF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

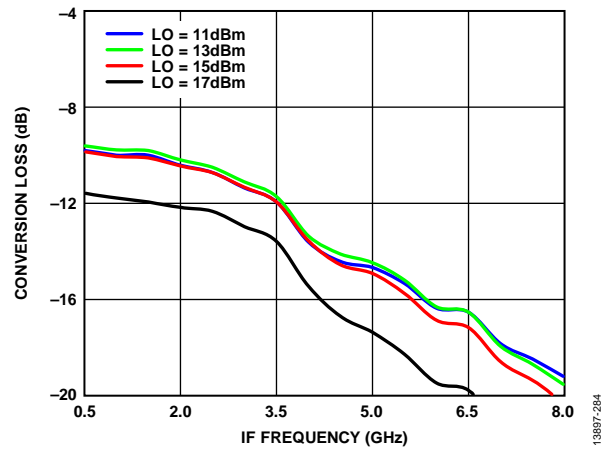


Figure 78. Conversion Loss vs. IF Frequency over Various LO Drives

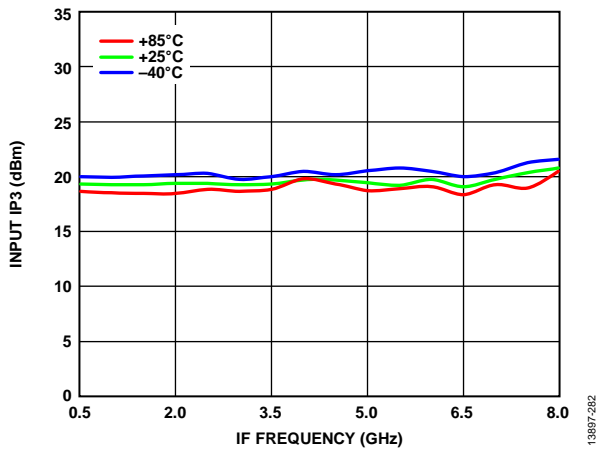


Figure 76. Input IP3 vs. IF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

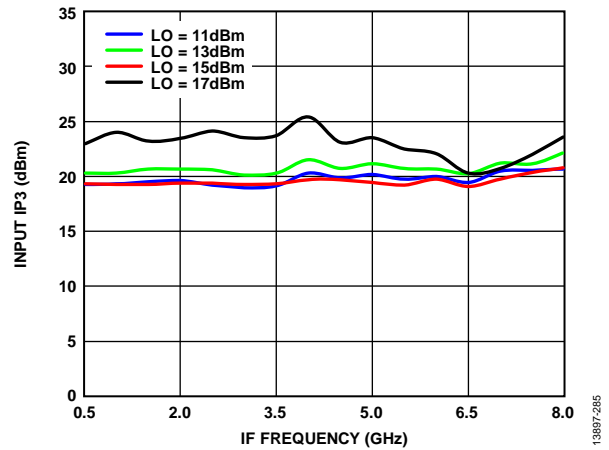


Figure 79. Input IP3 vs. IF Frequency over Various LO Drives

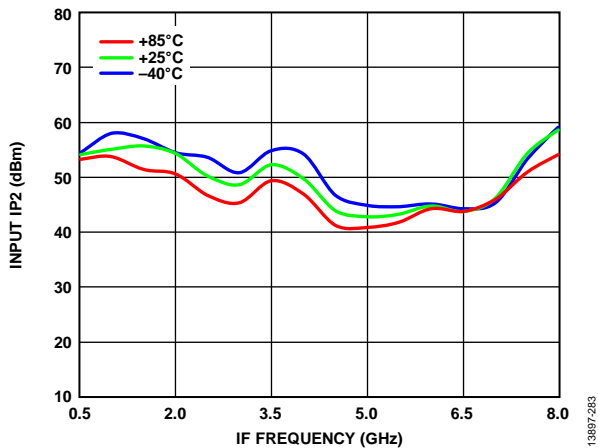


Figure 77. Input IP2 vs. IF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

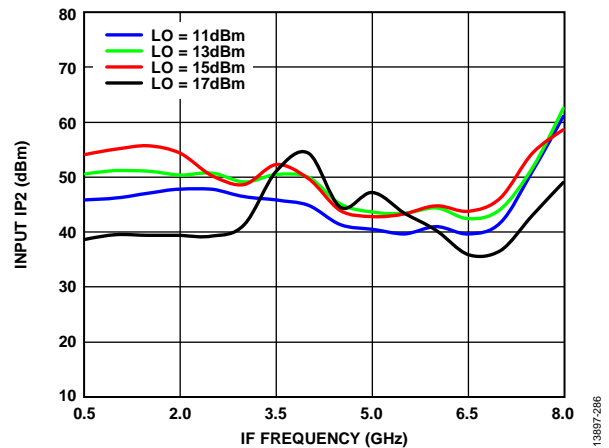


Figure 80. Input IP2 vs. IF Frequency over Various LO Drives

IF BANDWIDTH, LO = 34 GHz, LOWER SIDEBAND

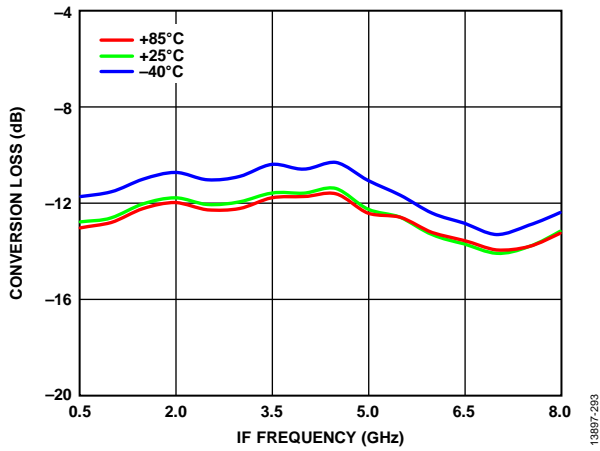


Figure 81. Conversion Loss vs. IF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

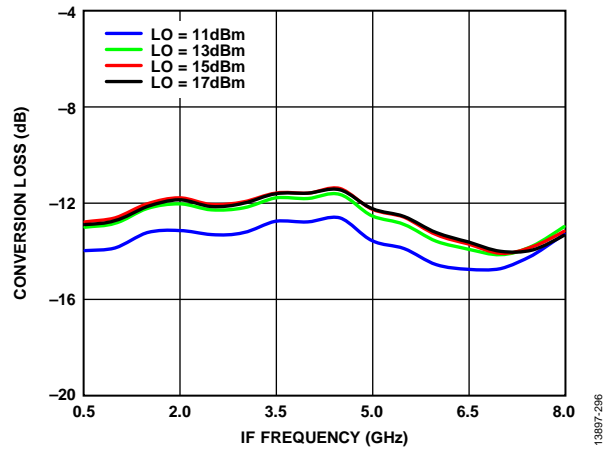


Figure 84. Conversion Loss vs. IF Frequency over Various LO Drives

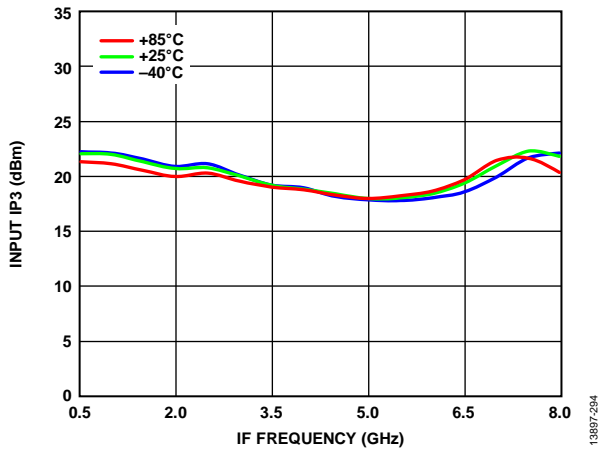


Figure 82. Input IP3 vs. IF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

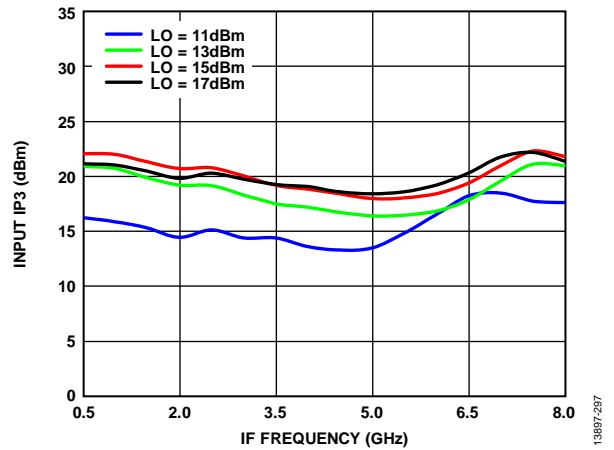


Figure 85. Input IP3 vs. IF Frequency over Various LO Drives

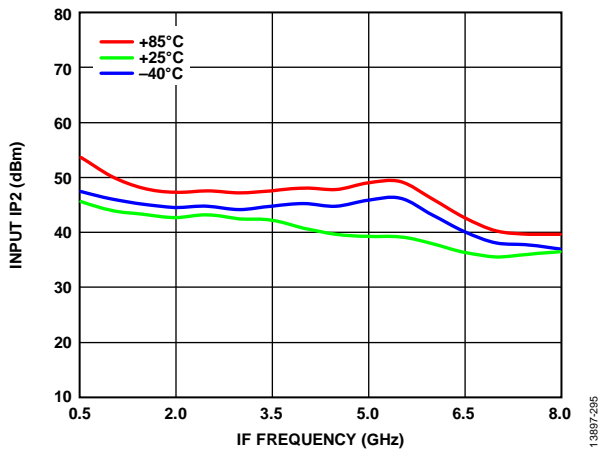


Figure 83. Input IP2 vs. IF Frequency over Various Temperatures, $P_{LO} = 15 \text{ dBm}$

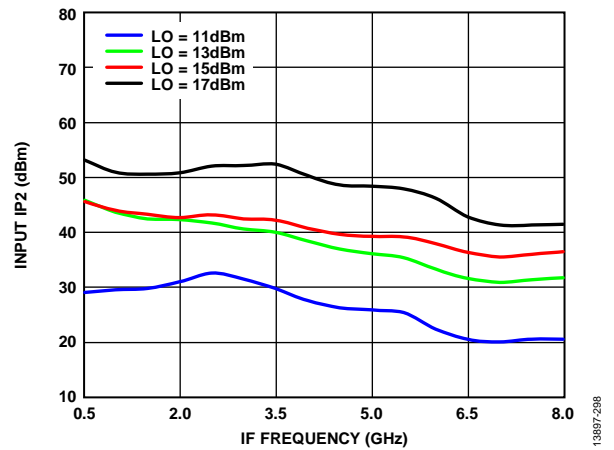


Figure 86. Input IP2 vs. IF Frequency over Various LO Drives

ISOLATION AND RETURN LOSS

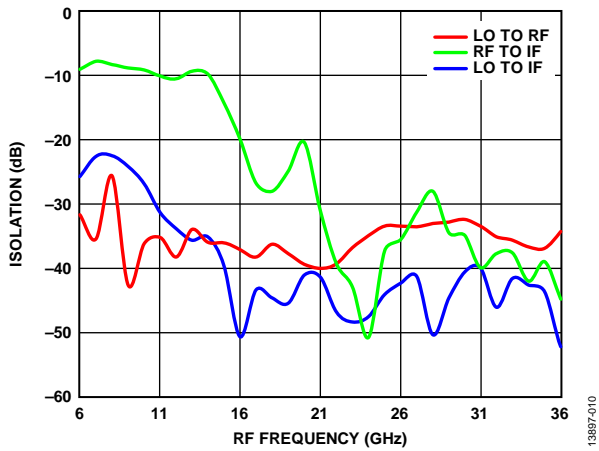


Figure 87. Isolation vs. RF Frequency for Various Isolations

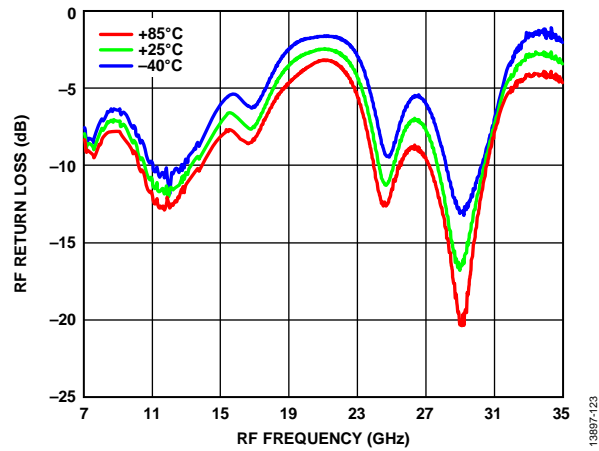


Figure 90. RF Return Loss vs. RF Frequency over Various Temperatures at $f_{LO} = 7$ GHz, $P_{LO} = 15$ dBm

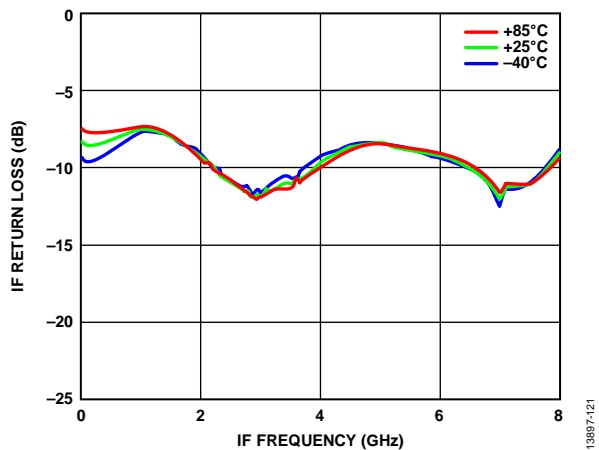


Figure 88. IF Return Loss vs. IF Frequency over Various Temperatures at $f_{LO} = 7$ GHz, $P_{LO} = 15$ dBm

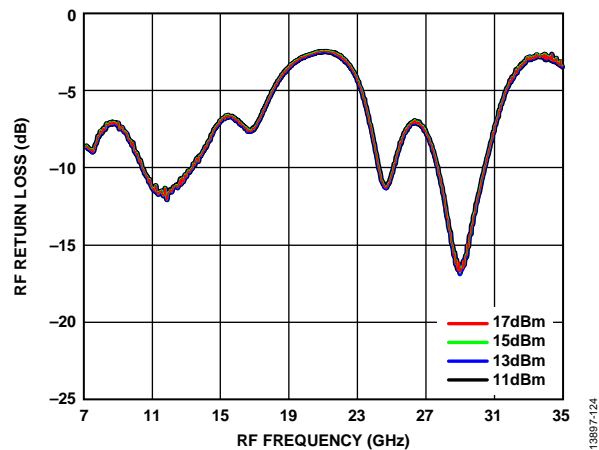


Figure 91. RF Return Loss vs. RF Frequency over Various LO Drives at $f_{LO} = 7$ GHz

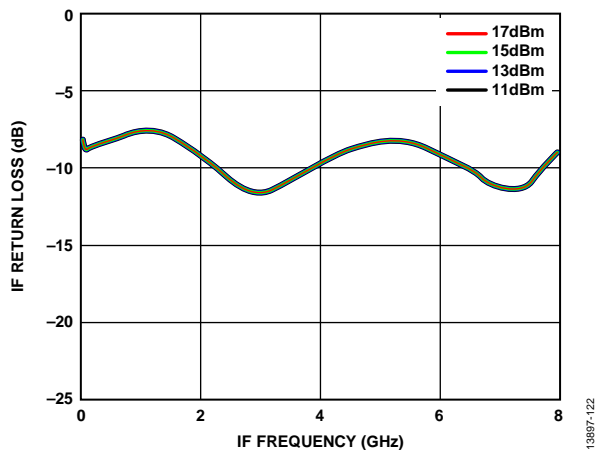


Figure 89. IF Return Loss vs. IF Frequency over Various LO Drives at $f_{LO} = 7$ GHz, $T_A = 25^\circ\text{C}$

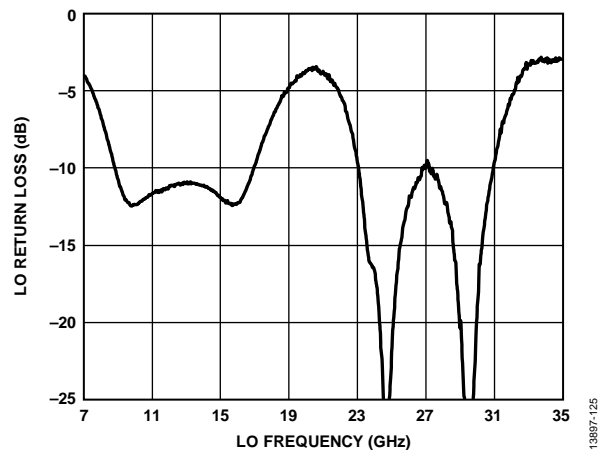


Figure 92. LO Return Loss vs. LO Frequency at $T_A = 25^\circ\text{C}$, $P_{LO} = 15$ dBm

SPURIOUS PERFORMANCE

LO Harmonics

When measuring the LO harmonics, the 15 dBm LO input power is applied at various LO frequencies.

All values are in decibels below the LO power level measured at the RF port. N/A means not applicable.

Table 6. LO Frequency vs. N × LO Spur at RF Port

| LO Frequency (GHz) | N × LO Spur at RF Port | | | |
|--------------------|------------------------|-----|-----|-----|
| | 1 | 2 | 3 | 4 |
| 8 | 33 | 29 | 50 | 46 |
| 10 | 41 | 34 | 69 | 47 |
| 18 | 36 | 59 | N/A | N/A |
| 28 | 32 | N/A | N/A | N/A |

All values are in decibels below the LO power level measured at the IF port. N/A means not applicable.

Table 7. LO Frequency vs. N × LO Spur at IF Port

| LO Frequency (GHz) | N × LO Spur at IF Port | | | |
|--------------------|------------------------|-----|-----|-----|
| | 1 | 2 | 3 | 4 |
| 8 | 49 | 73 | 97 | 113 |
| 10 | 55 | 80 | 100 | 118 |
| 18 | 68 | 110 | N/A | N/A |
| 28 | 65 | N/A | N/A | N/A |

M × N Spurious Outputs

Mixer spurious products are measured in decibels from either below the RF or the IF output power level. N/A means not applicable.

RF = 17.5 GHz at -10 dBm, and LO = 18 GHz at +15 dBm are applied. Spur values are (M × RF) - (N × LO).

| | | N × LO | | | | |
|--------|---|--------|-----|----|-----|-----|
| | | 0 | 1 | 2 | 3 | 4 |
| M × RF | 0 | N/A | 13 | 40 | N/A | N/A |
| | 1 | 18 | 0 | 54 | 50 | N/A |
| | 2 | 62 | 74 | 63 | 72 | 63 |
| | 3 | N/A | 66 | 75 | 71 | 74 |
| | 4 | N/A | N/A | 63 | 74 | 86 |

IF = 0.5 GHz at -10 dBm, and LO = 18 GHz at +15 dBm are applied. Spur values are (M × IF) + (N × LO).

| | | N × LO | | | | |
|--------|----|--------|----|----|-----|-----|
| | | 0 | 1 | 2 | 3 | 4 |
| M × IF | -4 | 86 | 79 | 66 | N/A | N/A |
| | -3 | 88 | 59 | 65 | N/A | N/A |
| | -2 | 67 | 39 | 62 | N/A | N/A |
| | -1 | 38 | 0 | 21 | N/A | N/A |
| | 0 | N/A | 2 | 26 | N/A | N/A |
| | +1 | 38 | 0 | 18 | N/A | N/A |
| | +2 | 67 | 40 | 53 | N/A | N/A |
| | +3 | 84 | 65 | 60 | N/A | N/A |
| | +4 | 87 | 77 | 60 | N/A | N/A |

THEORY OF OPERATION

The HMC774ALC3B is a general-purpose, double balanced mixer that can be used as an upconverter or a downconverter from 7 GHz to 34 GHz.

When used as a downconverter, the HMC774ALC3B downconverts RF between 7 GHz and 34 GHz to IF between dc and 8 GHz.

When used as an upconverter, the HMC774ALC3B upconverts IF between dc and 8 GHz to RF between 7 GHz and 34 GHz.

APPLICATIONS INFORMATION

EVALUATION BOARD

Figure 93 and Figure 94 show the top and cross sectional views of the evaluation board, which uses 4-layer construction, with a copper thickness of 0.5 oz (0.7 mil) and dielectric materials between each copper layer.

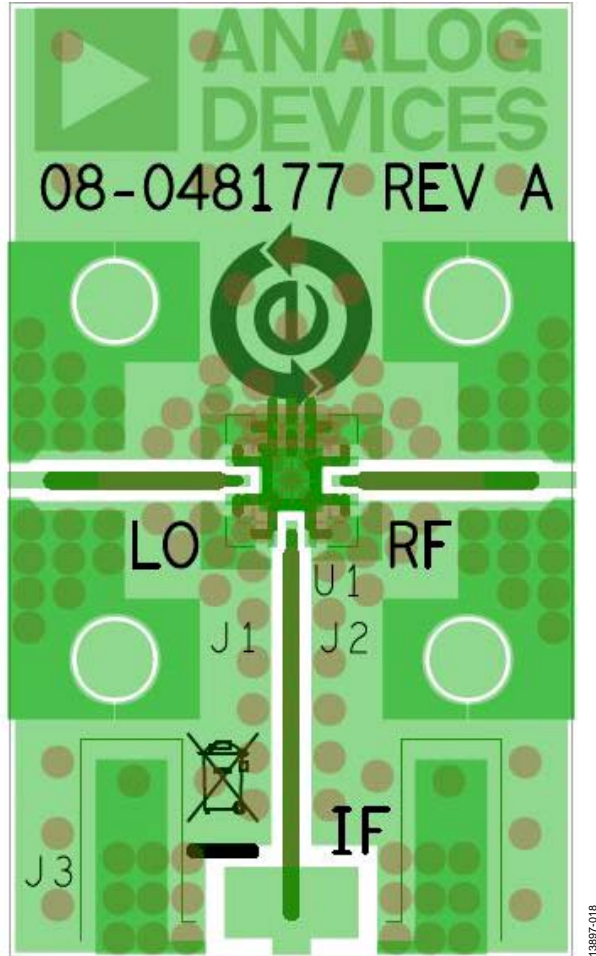


Figure 93. Evaluation Board Layout Top View



Figure 94. Evaluation Board Cross Sectional View

All RF traces are routed on Layer 1, and all other remaining layers are ground planes that provide a solid ground for RF transmission lines. The top dielectric material is Rogers 4350, offering low loss performance. The prepreg material in the middle sticks core layers together, which includes an Isola 370HR layer with copper traces above and below. Both the prepreg material and the Isola 370HR core layer are used to achieve required board finish thickness.

The RF transmission lines are designed using a coplanar waveguide (CPWG) model with a width of 18 mil and ground spacing of 13 mil for a characteristic impedance of 50 Ω. For optimal RF and thermal grounding, as many plated through vias as possible are arranged around the transmission lines and under the exposed pad of the package.

Figure 95 shows the actual EV1HMC774ALC3B evaluation board with component placement. Because the EV1HMC774ALC3B is a passive device, there is no requirement for external components. The LO, RF, and IF pins are internally dc-coupled. Use an external series capacitor when an operation is not required. Choose a value that stays within the necessary frequency range for each port. When an operation to dc is required, do not exceed the source and sink current ratings specified in the Absolute Maximum Ratings section.

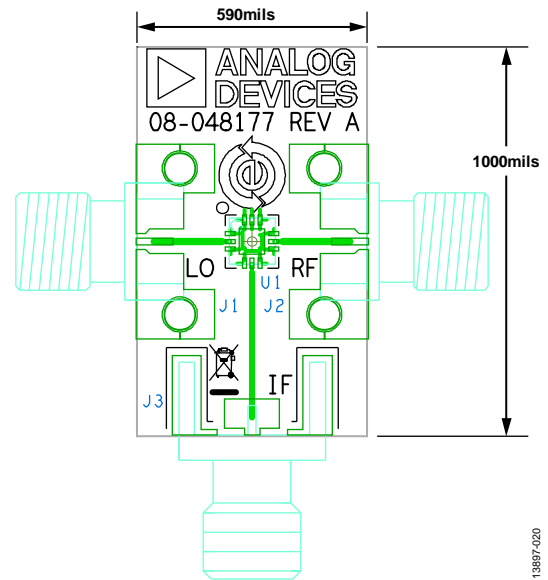


Figure 95. EV1HMC774ALC3B Evaluation Board

The EV1HMC774ALC3B evaluation board shown in Figure 95 is available for order from the Analog Devices, Inc., website at www.analog.com.

Figure 96 shows the Pb-free reflow solder profile.

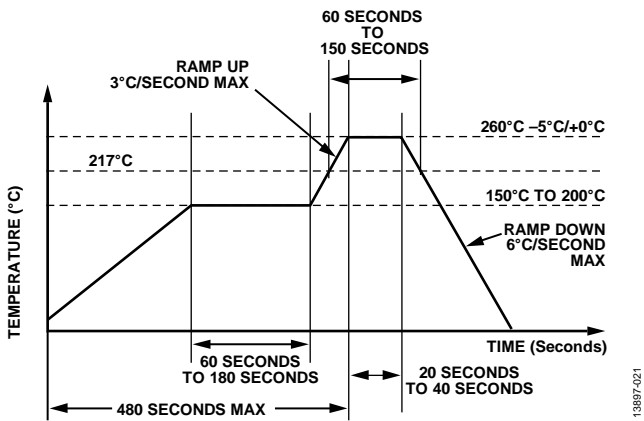


Figure 96. Pb-Free Reflow Solder Profile

Figure 97 shows the evaluation board schematic, and Table 8 lists the bill of materials for the EV1HMC774ALC3B evaluation board shown in Figure 95.

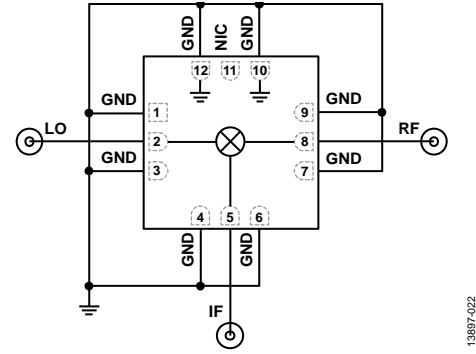


Figure 97. EV1HMC774ALC3B Evaluation Board Schematic

Table 8. Bill of Materials for the EV1HMC774ALC3B Evaluation Board

| Component | Description |
|------------------|--------------------------|
| J1, J2 | 2.92 mm connector |
| J3 | SMA connector |
| U1 | HMC774ALC3B |
| PCB ¹ | 08-048177 Evaluation PCB |

¹ 108-047919 is the raw bare PCB identifier. Reference the EV1HMC774ALC3B part number when ordering the complete evaluation PCB.

OUTLINE DIMENSIONS

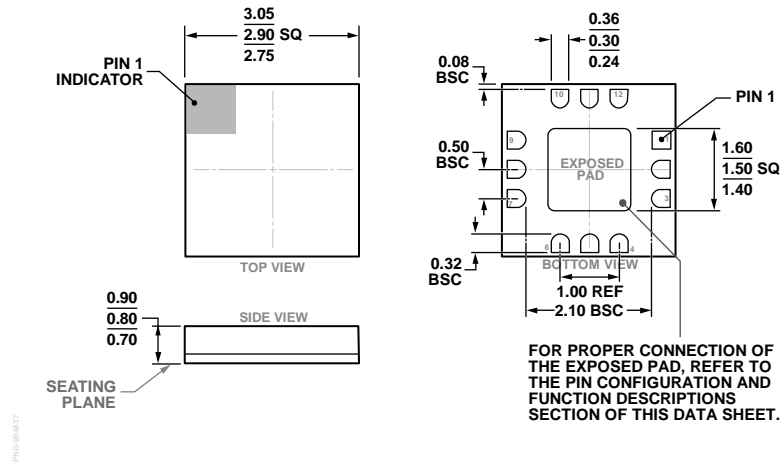


Figure 98. 12-Terminal Ceramic Leadless Chip Carrier [LCC]
(E-12-4)
Dimensions shown in millimeters

ORDERING GUIDE

| Model ¹ | Temperature Range | Moisture Sensitivity Level (MSL) Rating ² | Package Description | Package Option |
|--------------------|-------------------|--|---|----------------|
| HMC774ALC3B | -40°C to +85°C | MSL3 | 12-Terminal Ceramic Leadless Chip Carrier [LCC] | E-12-4 |
| HMC774ALC3BTR | -40°C to +85°C | MSL3 | 12-Terminal Ceramic Leadless Chip Carrier [LCC] | E-12-4 |
| HMC774ALC3BTR-R5 | -40°C to +85°C | MSL3 | 12-Terminal Ceramic Leadless Chip Carrier [LCC] | E-12-4 |
| EV1HMC774ALC3B | | | Evaluation PCB Assembly | |

¹ All models are RoHS Compliant Parts.

² See Figure 96 for the peak reflow temperature.